

## NE542 Dual Low-Noise Preamplifier

### Product Specification

#### Linear Products

#### DESCRIPTION

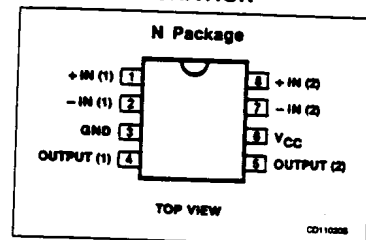
The NE542 is a dual preamplifier for the amplification of low level signals in applications requiring optimum noise performance. Each of the two amplifiers is completely independent, with individual internal power supply decoupler-regulator, providing 110dB supply rejection and 70dB channel separation. Other outstanding features include high gain (104dB), large output voltage swing ( $V_{CC}-2V_{P-P}$ ), and internal compensation to 10dB. The NE542 operates from a single supply across a range of 9 to 24V.

The NE542 is ideal for use in stereo phono, tape, or microphone preamps and other applications requiring low noise amplification of small signals.

#### FEATURES

- Low noise —  $0.7\mu V$  total input noise
- High gain — 104dB open-loop
- Single supply operation
- Wide supply range 9 to 24V
- Power supply rejection 110dB
- Large output voltage swing ( $V_{CC}-2V_{P-P}$ )
- Wide bandwidth 15MHz unity gain
- Power bandwidth 100kHz ( $15V_{P-P}$ )
- Internally-compensated (stable at 10dB)
- Short-circuit protected
- High slew rate  $5V/\mu s$

#### PIN CONFIGURATION



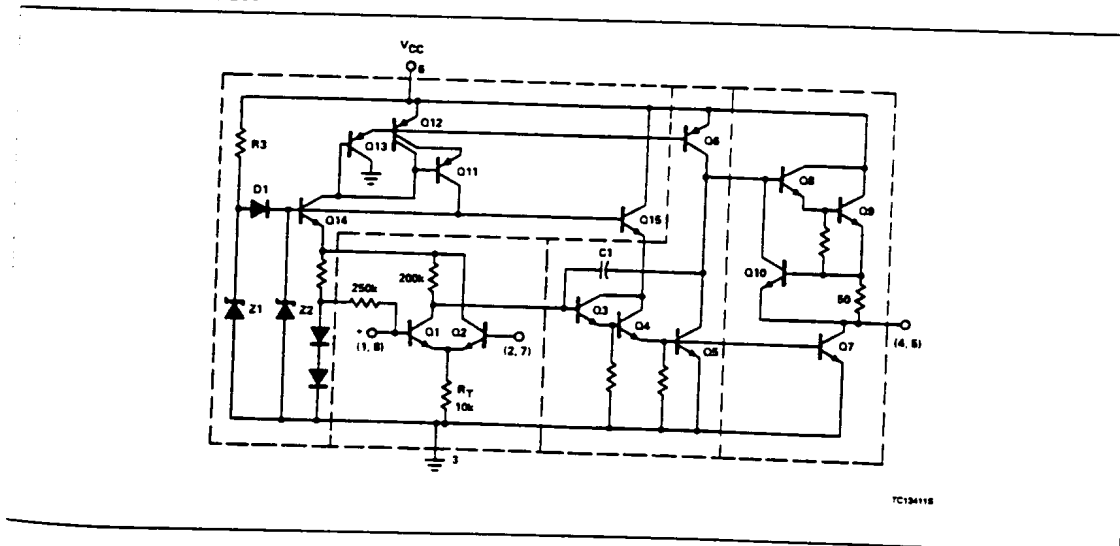
#### APPLICATIONS

- Tape preamplifier
- Phono preamplifier
- Microphone preamplifier

#### ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE
8-Pin Plastic DIP	0 to +70°C	NE542N

#### EQUIVALENT CIRCUIT



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### ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V <sub>CC</sub>	Supply voltage	+24	V
P <sub>D</sub>	Power dissipation	500	mW
T <sub>A</sub>	Operating ambient temperature range	0 to +70	°C
T <sub>STG</sub>	Storage temperature range	-65 to +150	°C
T <sub>SOLD</sub>	Lead soldering temperature (10sec max)	+300	= dc

### DC ELECTRICAL CHARACTERISTICS T<sub>A</sub> = 25°C; V<sub>CC</sub> = 14V, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
V <sub>CC</sub>	Supply voltage		9		24	V
I <sub>CC</sub>	Supply current	V <sub>CC</sub> = 9 to 18V, R <sub>L</sub> = ∞		9	15	mA
R <sub>IN</sub>	Input resistance Positive input Negative input			100 200		kΩ kΩ
R <sub>OUT</sub>	Output resistance	Open-loop		150		Ω

### AC ELECTRICAL CHARACTERISTICS T<sub>A</sub> = 25°C; V<sub>CC</sub> = 14V, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
A <sub>v</sub>	Voltage gain	Open-loop		160,000		V/V
I <sub>IN</sub>	Negative input current				0.5	mA
I <sub>OUT</sub>	Output current	Source Sink (linear operation)	8 2	14 3		mA mA
V <sub>OUT</sub>	Output voltage swing		V <sub>CC</sub> - 2.5	V <sub>CC</sub> - 2		V
SR	Small signal bandwidth Slew rate			15 5		MHz V/μs
P <sub>BW</sub>	Power bandwidth	15V <sub>p,p</sub>		100		kHz
V <sub>IN</sub>	Maximum input voltage	Linear operation, < 2.5% distortion			300	mV <sub>RMS</sub>
PSRR	Power supply rejection ratio	f = 60, 120Hz f = 1kHz		100 110		dB dB
	Channel separation	f = 1kHz	40	70		dB
THD	Total harmonic distortion	40dB gain, f = 1kHz		0.1	0.3	%
	Total equivalent input noise	R <sub>S</sub> = 600Ω, 100 - 10,000Hz		0.7	1.2	μV <sub>RMS</sub>
	Noise figure	R <sub>S</sub> = 50kΩ, 10 - 10,000Hz		1.2		dB
		R <sub>S</sub> = 20kΩ, 10 - 10,000Hz		1.2		dB
		R <sub>S</sub> = 10kΩ, 10 - 10,000Hz		1.5		dB
		R <sub>S</sub> = 5kΩ, 10 - 10,000Hz		2.4		dB

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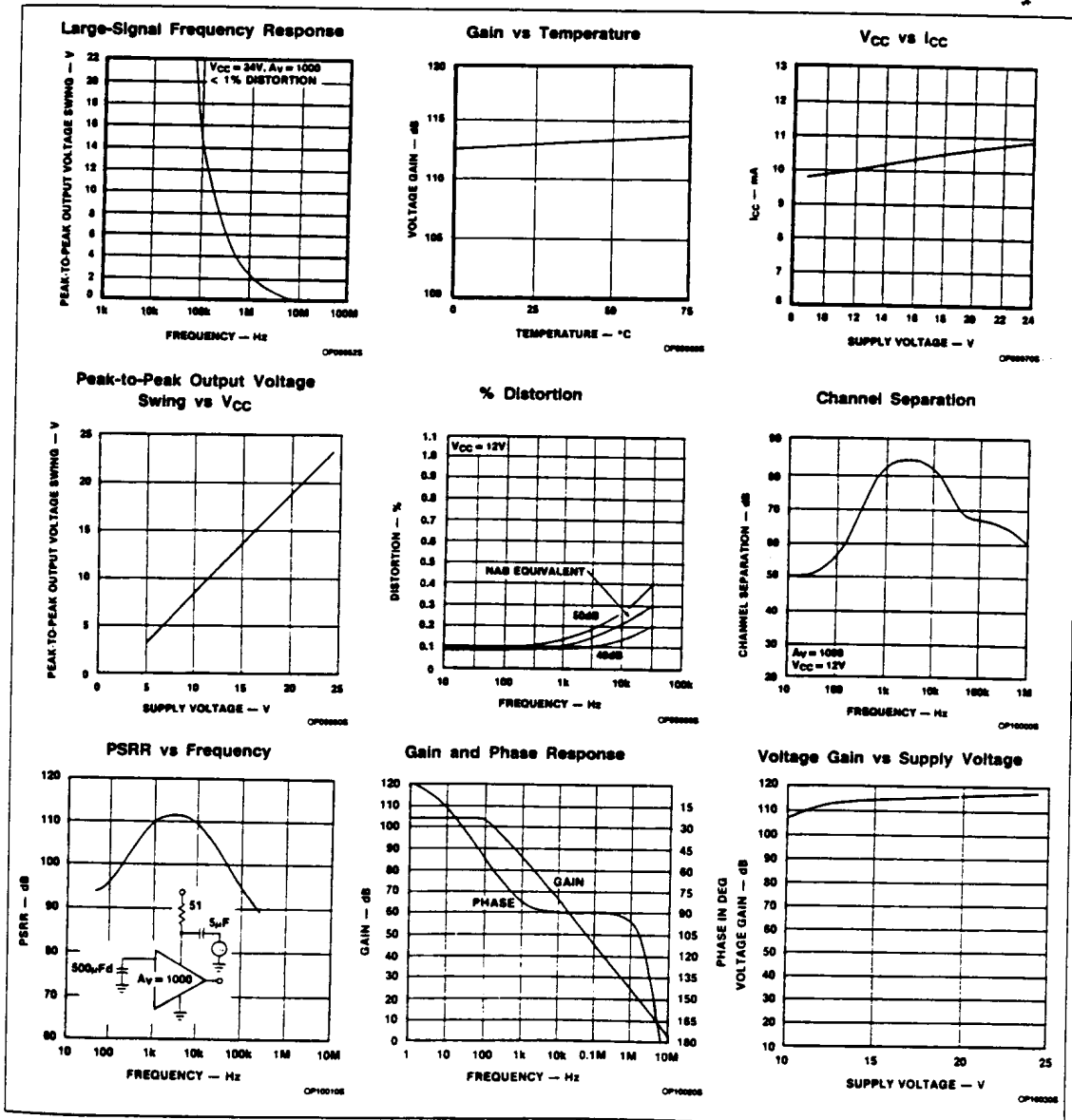
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### TYPICAL PERFORMANCE CHARACTERISTICS



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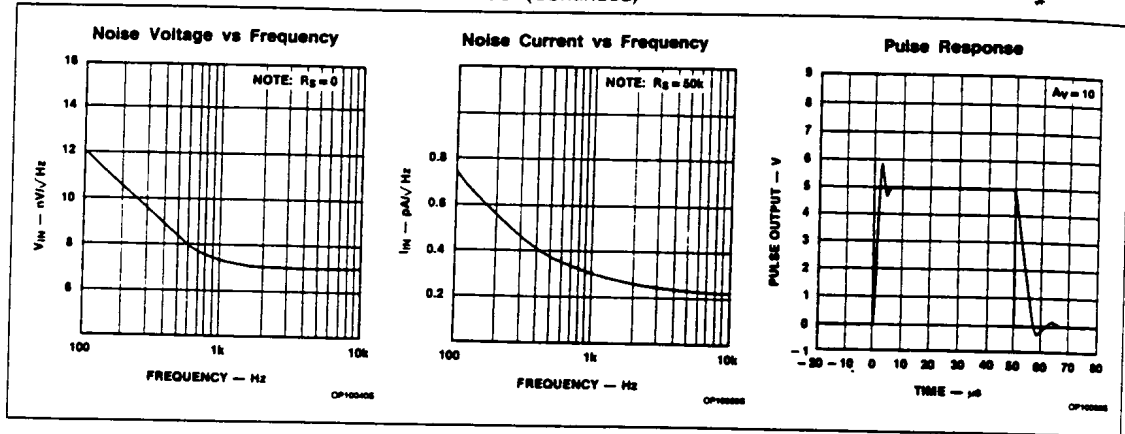
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### TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



### TYPICAL APPLICATIONS

